



AP7361

1A LOW DROPOUT ADJUSTABLE AND FIXED-MODE REGULATOR WITH ENABLE

Description

The AP7361 is a 1A, adjustable and fixed output voltage, ultra-low dropout linear regulator with enable. The device includes pass element, error amplifier, band-gap reference, current limit and thermal shutdown circuitry. The device is turned on when EN pin is set to logic high level.

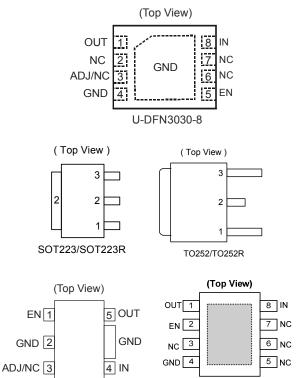
The characteristics of the low dropout voltage and low quiescent current make it suitable for low to medium power applications, for example, laptop computers, audio and video applications, and battery powered devices. The typical quiescent current is approximately $70\mu A$. Built-in current-limit and thermal-shutdown functions prevent IC from damage in fault conditions.

The AP7361 is available in U-DFN3030-8, SOT89-5, SOT223, TO252 and SO-8EP package.

Features

- Wide input voltage range: 2.2V 6V
- 150mV Very Low Dropout at 300mA Load
- 500mV Very Low Dropout at 1A Load
- Low Quiescent Current (I_Q): 70µA Typical
- Adjustable Output Voltage Range: 1V to 5.0V
- Fixed Output Options: 1V to 3.3V
- Very Fast Transient Response
- High PSRR
- Accurate Voltage Regulation
- Current Limiting and Short Circuit Protection
- Thermal Shutdown Protection
- Stable with Ceramic Output Capacitor $\ge 2.2 \mu F$
- Ambient Temperature Range -40°C to +85°C
- U-DFN3030-8, SOT89-5, SOT223/SOT223R, TO252/TO252R and SO-8EP
- Available in "Green" Molding Compound (No Br, Sb)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



SO-8EP

Applications

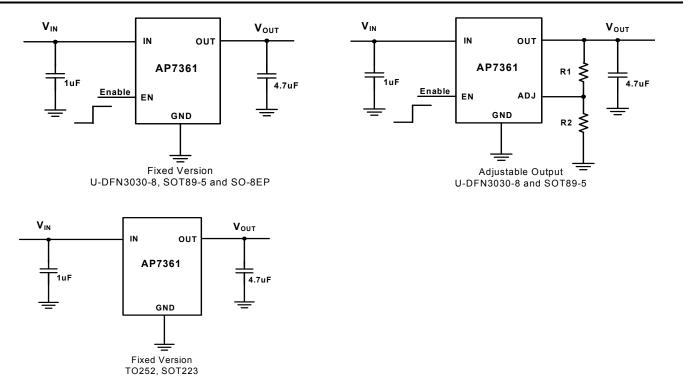
- Servers and Laptops
- FPGA and DSP Core or I/O Power
- TV, and Home Electrical Appliances

SOT89-5

- Battery-Powered Devices
- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 - 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit

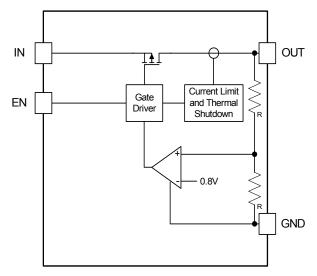


Pin Descriptions

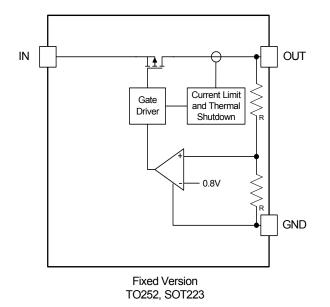
Pin		Pin Number						Function	
Name	U-DFN3030-8	SOT89-5	TO252	TO252R	SOT223	SOT223R	SO-8EP	Function	
IN	8	4	1	3	1	3	8	The input of the regulator. Bypass to ground through at least 1µF ceramic capacitor.	
OUT	1	5	3	2	3	2	1	The output of the regulator. Bypass to ground through at least 2.2μ F ceramic capacitor. For improved ac load response a larger capacitor is recommended.	
GND	4	2	2	1	2	1	4	Ground.	
ADJ	3	3	NA	NA	NA	NA	NA	Adjustable voltage version only – a resistor divider from this pin to the OUT pin and ground sets the output voltage.	
EN	5	1	NA	NA	NA	NA	2	Enable input, active high.	
NC	2, 6, 7	NA	NA	NA	NA	NA	3, 5, 6, 7	No connection.	

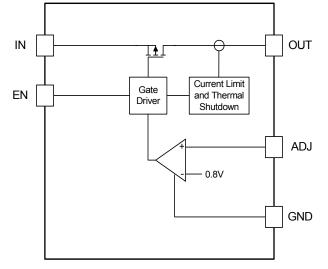


Functional Block Diagram



Fixed Version U-DFN3030-8, SOT89-5 and SO-8EP





Adjustable Version U-DFN3030-8 and SOT89-5



Symbol	Param	eter	Ratings	Unit	
ESD HBM	Human Body Model ESD Protection	า	> 2	KV	
ESD MM	Machine Model ESD Protection (No	ote 5)	> 200	V	
VIN	Input Voltage		6.5	V	
	OUT, ADJ, EN Voltage	OUT, ADJ, EN Voltage		V	
TJ	Operating Junction Temperature Ra	ange	-40 to +150	°C	
T _{ST}	Storage Temperature Range		-65 to +150	°C	
PD	Power Dissipation (Note 4)		Internally limited by maximum junction temperature of +150°C		
		U-DFN3030-8	1700		
		TO252	1250		
PD	Power Dissipation (Note 4)	SOT223	1100	mW	
		SOT89-5	800		
		SO-8EP	1190		

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Notes: 4. Ratings apply to ambient temperature at +25°C.

5. ESD MM rating at 150V for EN pin in SOT89-5L package.

Stresses greater than the 'Absolute Maximum Ratings' specified above, may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V _{IN}	Input Voltage	2.2	6.0	V
I _{OUT}	Output Current (Note 6)	0	1.0	А
T _A	Operating Ambient Temperature	-40	+85	С°

Note: 6. The device maintains a stable, regulated output voltage without a load current. When the output current is large, attention should be given to the limitation of the package power dissipation.



Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit	
V _{REF}	FB Reference Voltage	I _{OUT} = 10mA, T _A = +25°C		0.8		V	
I _{ADJ}	ADJ Pin Leakage			0.1	0.5	μA	
lq	Input Quiescent Current	Enabled, I _{OUT} = 0A		70	90	μA	
ISHDN	Input Shutdown Current	$V_{EN} = 0V, I_{OUT} = 0A$	-1	0.05	1	μA	
		I _{OUT} = 100mA, T _A = +25°C	-1		1		
V _{OUT}	Output Voltage Accuracy	I_{OUT} = 100mA, -40°C ≤ T_A ≤ +85°C	-2		2	%	
		Over V_{IN} , I_{OUT} , and T_A	-3	±0.5	3		
Δνουτ	Line Degulation	$V_{IN} = V_{OUT} + 1V$ to $T_A = +25^{\circ}C$		0.01	0.1	0/ 0/	
$\Delta VIN \times V_{OUT}$	Line Regulation	$6V, I_{OUT} = 100 \text{mA}$ $-40^{\circ}\text{C} \le T_{A} \le +85^{\circ}\text{C}$			0.2	%/V	
	Lead Devidefier	I _{OUT} from 1mA to 300mA	-1.0	0.5	1.0	%	
ΔV_{OUT} / V_{OUT}	Load Regulation	I _{OUT} from 1mA to 1A	-1.0	0.5	1.0	%	
		I _{OUT} = 300mA		150	200		
VDROPOUT	Dropout Voltage (Note 7)	I _{OUT} = 500mA		250	350	mV	
		I _{OUT} = 1A		500	700		
VIL	EN Input Logic Low Voltage		0		0.3	V	
VIH	EN Input Logic High Voltage		1.0		VIN	V	
I _{EN}	EN Input Leakage	$V_{IN} = 6V, V_{EN} = 0V \text{ or } 6V$	-0.1	0.01	0.1	μA	
ILIMIT	Current Limit	$V_{IN} = V_{OUT} + 1V$	1.1	1.5		А	
ISHORT	Short-Circuit Current	V _{IN} = V _{OUT} +1V, Output Voltage < 15% V _{OUT}		200		mA	
	Power Supply Rejection Ratio	f = 1KHz, I _{OUT} = 100mA	60	65		dB	
PSRR	(Note 8)	f = 10KHz, I _{OUT} = 100mA		45			
t _{ST}	Start-Up Time	V_{OUT} = 3V, C_{OUT} = 1 μ F, R_L = 30 Ω		200		μs	
$\frac{\Delta VOUT}{\Delta T_A \times VOUT}$	Output Voltage Temperature Coefficient	I _{OUT} = 100mA, -40°C ≤ T _A ≤ +85°C		±130		ppm/°C	
T _{SHDN}	Thermal Shutdown Threshold			150		°C	
T _{HYS}	Thermal Shutdown Hysteresis			20		°C	
		U-DFN3030-8 (Note 9)		70			
		TO252 (Note 9)		95			
θ _{JA}	Thermal Resistance Junction-to-Ambient	SOT223 (Note 9)		110		°C/W	
		SOT89-5 (Note 9)		150			
		SO-8EP (Note 9)		100			

Electrical Characteristics (@T_A = +25°C, V_{IN} = V_{OUT} +1V, C_{IN} = 1µF, C_{OUT} = 4.7µF, V_{EN} = V_{IN} unless otherwise specified.)

7. Dropout voltage is the voltage difference between the input and the output at which the output voltage drops 2% below its Notes:

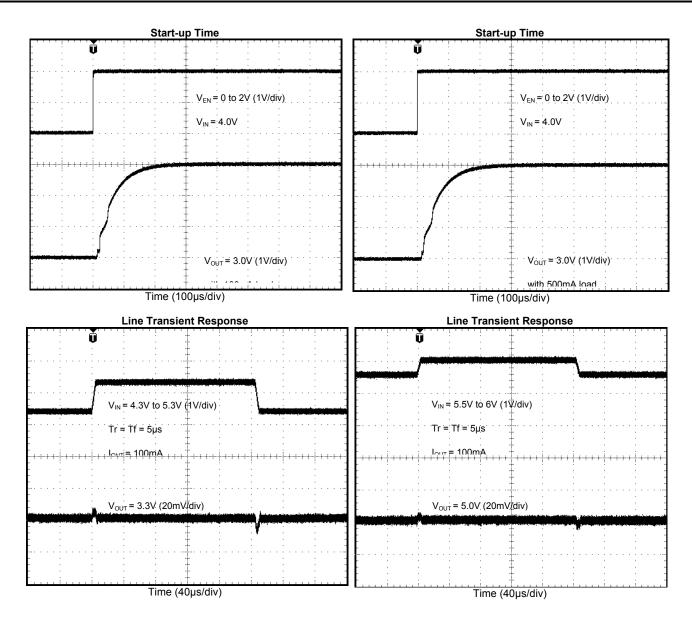
nominal value. This parameter only applies to output voltages above 1.5V since minimum V_{IN} = 2.2V.

 For V_{IN} ≥ 2.5V and V_{IN} = V_{OUT} +1V. For V_{IN} < 2.5V, the PSRR performance may be reduced.
Test condition : DFN3030E-8, SO-8EP device mounted on 2"x2", FR-4 substrate PCB, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane. TO252 device mounted on 2"x2" FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. SOT223 the device is mounted on FR-4 substrate PC board, with minimum recommended pad layout. SOT223 the device is mounted on FR-4 substrate PC board, with minimum recommended pad layout. substrate PC board, with minimum recommended pad layout

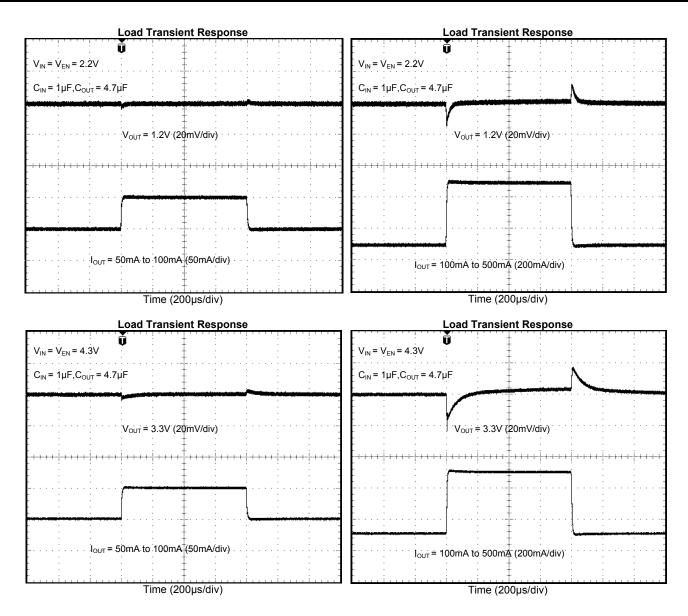


AP7361

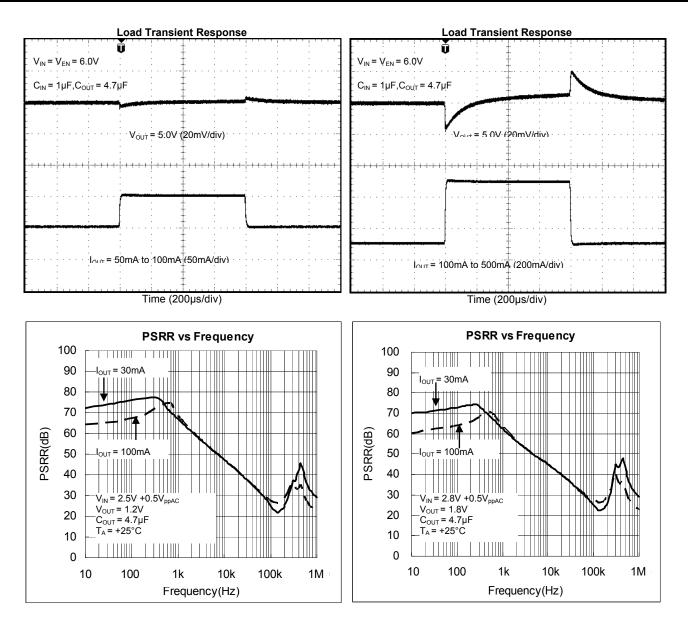
Typical Performance Characteristics



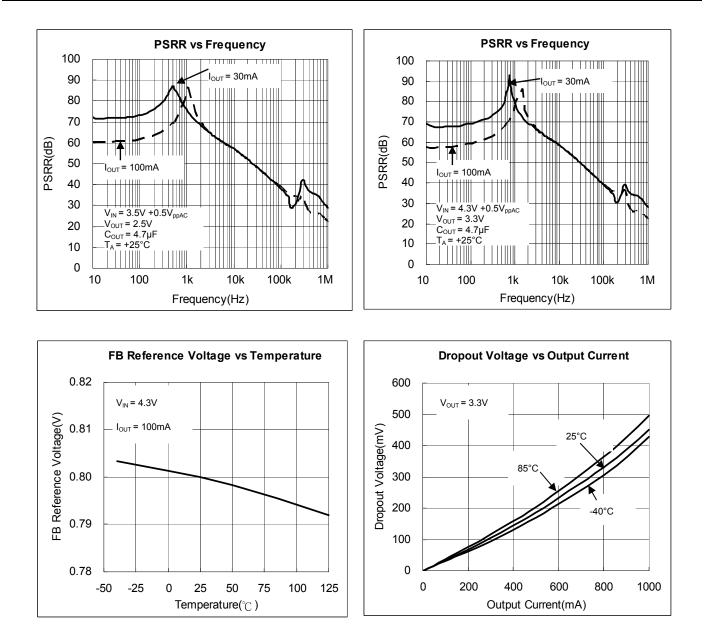




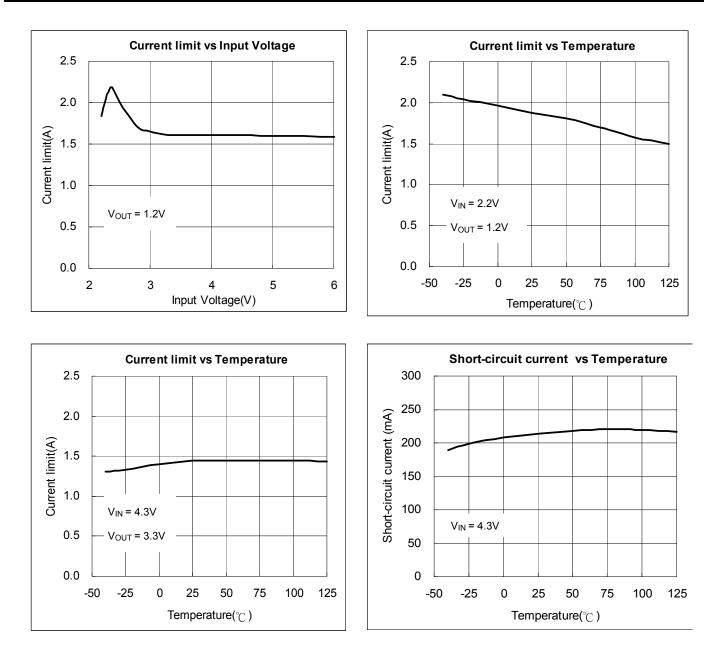




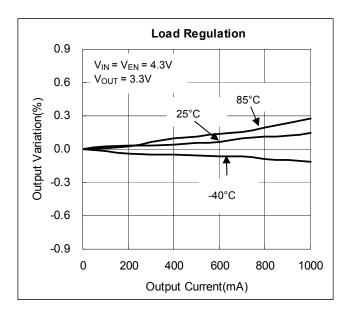


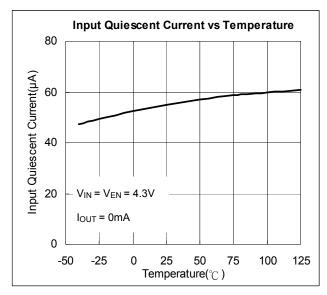


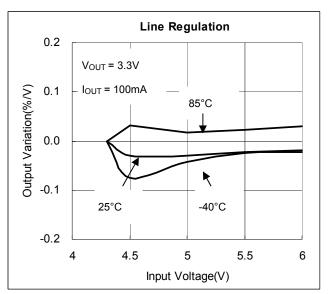


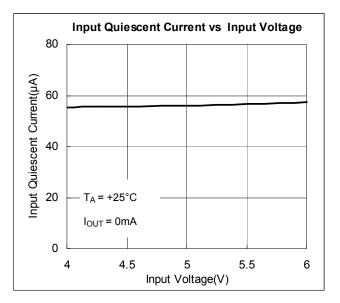














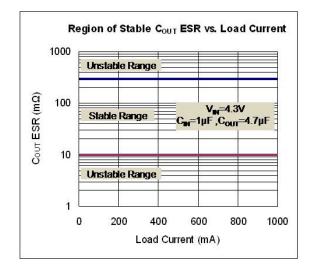
Application Information

Input Capacitor

A 1µF ceramic capacitor is recommended between IN and GND pins to decouple input power supply glitch and noise. The amount of the capacitance may be increased without limit. This input capacitor must be located as close as possible to the device to assure input stability and reduce noise. For PCB layout, a wide copper trace is required for both IN and GND pins. A lower ESR capacitor type allows the use of less capacitance, while higher ESR type requires more capacitance.

Output Capacitor

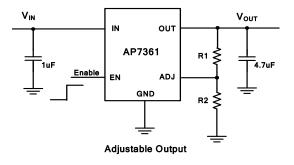
The output capacitor is required to stabilize and improve the transient response of the LDO. The AP7361 is stable with very small ceramic output capacitors. Using a ceramic capacitor value that is at least 2.2μ F with $10m\Omega \leq ESR \leq 300m\Omega$ on the output ensures stability. Higher capacitance values help to improve line and load transient response. The output capacitance may be increased to keep low undershoot and overshoot. Output capacitor must be placed as close as possible to OUT and GND pins.



Adjustable Operation

Adjustable operation is not available in the SOT223 TO252 and SO-8EP package.

The AP7361 provides output voltage from 0.8V to 5.0V through external resistor divider as shown below.



The output voltage is calculated by:

$$V_{OUT} = V_{REF} \left(1 + \frac{R_1}{R_2} \right)$$

Where V_{REF} = 0.8V (the internal reference voltage)

Rearranging the equation will give the following that is used for adjusting the output to a particular voltage:

$$R_1 = R_2 \left(\frac{V_{OUT}}{V_{REF}} - 1 \right)$$

To maintain the stability of the internal reference voltage, R_2 need to be kept smaller than 80k Ω .



Application Information

No Load Stability

Other than external resistor divider, no minimum load is required to keep the device stable. The device will remain stable and regulated in no load condition.

ON/OFF Input Operation

The ON/OFF feature is not available in the SOT223 and TO252 package.

The AP7361 is turned on by setting the EN pin high, and is turned off by pulling it low. If this feature is not used, the EN pin should be tied to IN pin to keep the regulator output on at all time. To ensure proper operation, the signal source used to drive the EN pin must be able to swing above and below the specified turn-on/off voltage thresholds listed in the Electrical Characteristics section under V_{IL} and V_{IH} .

Current Limit Protection

When output current at OUT pin is higher than current limit threshold, the current limit protection will be triggered and clamp the output current to prevent over-current and to protect the regulator from damage due to overheating.

Short Circuit Protection

When OUT pin is short-circuit to GND, short circuit protection will be triggered and clamp the output current to approximately 200mA. Full current is restored when the output voltage exceeds 15% of Vout. This feature protects the regulator from over-current and damage due to overheating.

Thermal Shutdown Protection

Thermal protection disables the output when the junction temperature rises to approximately +150°C, allowing the device to cool down. When the junction temperature reduces to approximately +130°C the output circuitry is enabled again. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the heat dissipation of the regulator, protecting it from damage due to overheating.

Ultra Fast Start-up

After enabled, the AP7361 is able to provide full power in as little as tens of microseconds, typically 200µs, without sacrificing low ground current. This feature will help load circuitry move in and out of standby mode in real time, eventually extend battery life for mobile phones and other portable devices.

Low Quiescent Current

The AP7361, consuming only around 70µA for all input range, provides great power saving in portable and low power applications.

Power Dissipation

The device power dissipation and proper sizing of the thermal plane that is connected to the thermal pad is critical to avoid thermal shutdown and ensure reliable operation. Power dissipation of the device depends on input voltage and load conditions and can be calculated by:

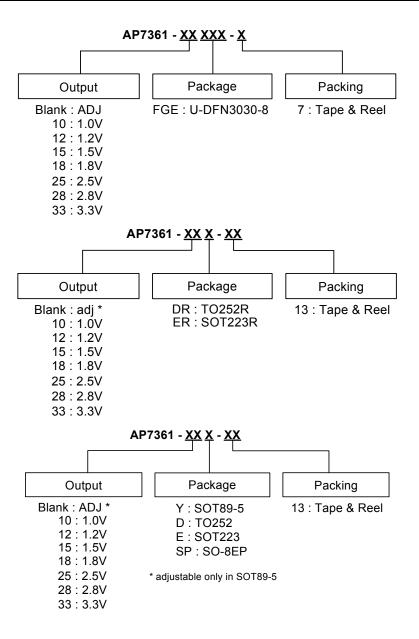
$$P_D = (V_{IN} - V_{OUT}) X I_{OUT}$$

The maximum power dissipation, handled by the device, depends on the maximum junction to ambient thermal resistance, maximum ambient temperature, and maximum device junction temperature, which can be calculated by the equation in the following:

$$P_D(max@T_A) = \frac{(+150°C - T_A)}{R_{\theta JA}}$$



Ordering Information



Part Number	Baakaga Cada	Packaging	7"/13" Tape and Reel		
Fait Number	Package Code	Packaging	Quantity	Part Number Suffix	
AP7361-XXFGE-7	FGE	UDFN3030-8	3000/Tape & Reel	-7	
AP7361-XXY-13	Y	SOT89-5	2500/Tape & Reel	-13	
AP7361-XXD-13	D	TO252	2500/Tape & Reel	-13	
AP7361-XXDR-13	DR	TO252R	2500/Tape & Real	-13	
AP7361-XXE-13	E	SOT223	2500/Tape & Reel	-13	
AP7361-XXER-13	ER	SOT223R	2500/Tape & Reel	-13	
AP7361-XXSP-13	SP	SO-8EP	2500/Tape & Reel	-13	



Marking Information

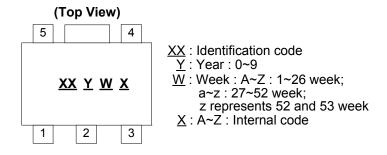
(1) U-DFN3030-8



 $\begin{array}{l} \underline{XX} : \text{Identification Code} \\ \underline{Y} : \text{Year} : 0~9 \\ \underline{W} : \text{Week} : A~Z : 1~26 \text{ week}; \\ a~z : 27~52 \text{ week}; \text{ z represents} \\ 52 \text{ and } 53 \text{ week} \\ \underline{X} : A~Z : \text{Internal code} \end{array}$

Device	Package	Identification Code
AP7361ADJ	U-DFN3030-8	PA
AP7361-10	U-DFN3030-8	PB
AP7361-12	U-DFN3030-8	PC
AP7361-15	U-DFN3030-8	PD
AP7361-18	U-DFN3030-8	PE
AP7361-25	U-DFN3030-8	PF
AP7361-28	U-DFN3030-8	PG
AP7361-33	U-DFN3030-8	PH

(2) SOT89-5



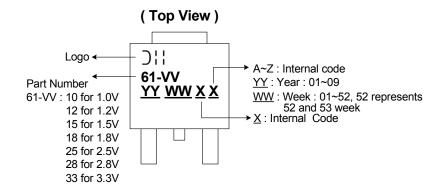
Device	Package	Identification Code
AP7361ADJ	SOT89-5	PA
AP7361-10	SOT89-5	PB
AP7361-12	SOT89-5	PC
AP7361-15	SOT89-5	PD
AP7361-18	SOT89-5	PE
AP7361-25	SOT89-5	PF
AP7361-28	SOT89-5	PG
AP7361-33	SOT89-5	PH



Marking Information (cont.)

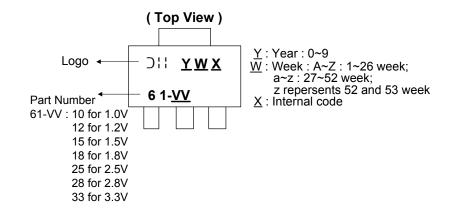
(3) TO252

Pin 1: V_{IN}, Pin 2: GND, Pin 3: V_{OUT}



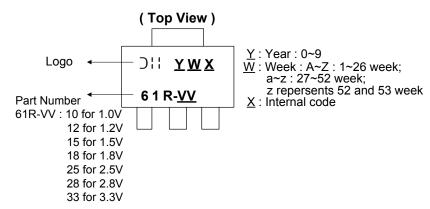
(4) SOT223

Pin 1: V_{IN}, Pin 2: GND, Pin 3: V_{OUT}



(5) SOT223R

Pin 1: GND, Pin 2: VOUT, Pin 3: VIN

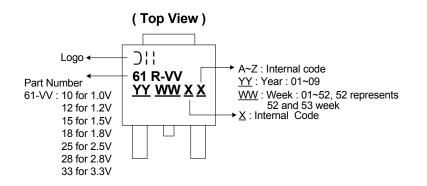




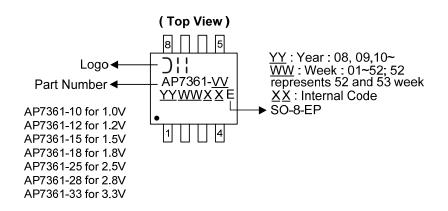
Marking Information (cont.)

(6) TO252-R

Pin 1: GND, Pin 2: V_{OUT}, Pin 3: V_{IN}



(7) SO-8EP

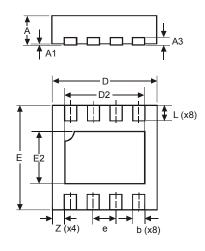




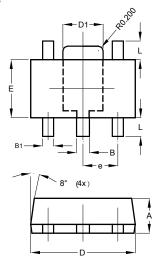
Package Outline Dimensions (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(1): U-DFN3030-8



(2): SOT89-5

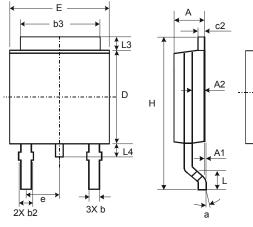


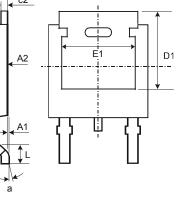
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	_ H

U-DFN3030-8						
Type E						
Dim	Min	Max	Тур			
Α	0.57	0.63	0.60			
A1	0	0.05	0.02			
A3	_	_	0.15			
b	0.20	0.30	0.25			
D	2.95	3.05	3.00			
D2	2.15	2.35	2.25			
Ε	2.95	3.05	3.00			
е	-	-	0.65			
E2	1.40	1.60	1.50			
L	0.30	0.60	0.45			
Ζ	_	_	0.40			
All I	Dimens	sions ir	n mm			

SOT89-5						
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.44	0.54	0.48			
С	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
Е	2.40	2.60	2.50			
е	-	-	1.50			
н	3.95	4.25	4.10			
L	0.65	0.95	0.80			
All	Dimens	sions in	mm			

(3): TO252





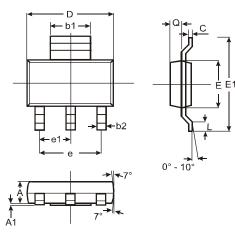
TO252					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
c2	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Η	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	_		
All	Dimen	sions i	n mm		



Package Outline Dimensions (cont.) (All dimensions in mm.)

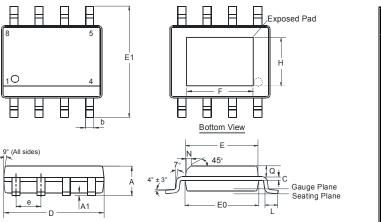
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(4): SOT223 and SOT223R



	SOT223						
Dim	Dim Min Max Typ						
Α	1.55	1.65	1.60				
A1	0.010	0.15	0.05				
b1	2.90	3.10	3.00				
b2	0.60	0.80	0.70				
С	0.20	0.30	0.25				
D	6.45	6.55	6.50				
Е	3.45	3.55	3.50				
E1	6.90	7.10	7.00				
е			4.60				
e1			2.30				
L	0.85	1.05	0.95				
Q	0.84	0.94	0.89				
All [Dimens	ions in	mm				

(5): SO-8EP



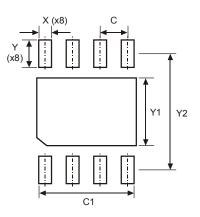
SO-8EP (SOP-8L-EP)				
Dim	Min	Max	Тур	
Α	1.40	1.50	1.45	
A1	0.00	0.13	-	
q	0.30	0.50	0.40	
c	0.15	0.25	0.20	
D	4.85	4.95	4.90	
Е	3.80	3.90	3.85	
E0	3.85	3.95	3.90	
E1	5.90	6.10	6.00	
е	-	-	1.27	
F	2.75	3.35	3.05	
Н	2.11	2.71	2.41	
L	0.62	0.82	0.72	
Ν	-	-	0.35	
Q	0.60	0.70	0.65	
All Dimensions in mm				



Suggested Pad Layout

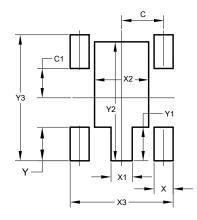
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1): U-DFN3030-8



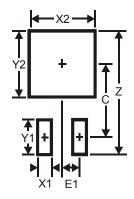
Dimensions	Value (in mm)
С	0.65
C1	2.35
Х	0.30
Y	0.65
Y1	1.60
Y2	2.75

(2): SOT89-5



Dimensions	Value (in mm)
С	1.500
C1	1.050
Х	0.680
X1	0.760
X2	1.930
X3	3.680
Y	1.200
Y1	1.200
Y2	4.250
Y3	4.500

(3): TO252



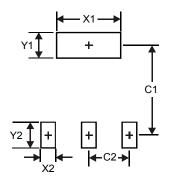
Dimensions	Value (in mm)
Z	11.6
X1	1.5
X2	7.0
Y1	2.5
Y2	7.0
С	6.9
E1	2.3



Suggested Pad Layout (cont.)

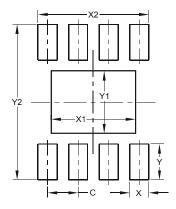
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(4): SOT223 and SOT223R



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

(5): SO-8EP



Dimensions	Value(in mm)
С	1.270
Х	0.802
X1	3.502
X2	4.612
Y	1.505
Y1	2.613
Y2	6.500



AP7361

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